

Vishay Siliconix

Improved Quad CMOS Analog Switches

DESCRIPTION

The DG201B, DG202B analog switches are highly improved versions of the industry-standard DG201A, DG202. These devices are fabricated in Vishay Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. The DG201B and DG202B can handle up to \pm 22 V input signals, and have an improved continuous current rating of 30 mA. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply voltages in the off condition.

The DG201B is a normally closed switch and the DG202B is a normally open switch. (see Truth Table.)

FEATURES

- ± 22 V supply voltage rating
- TTL and CMOS compatible logic
- Low on-resistance R_{DS(on)}: 45 Ω
- Low leakage I_{D(on)}: 20 pA
- Single supply operation possible
- Extended temperature range
- Fast switching t_{ON}: 120 ns
- Low glitching Q: 1 pC
- Compliant to RoHS Directive 2002/95/EC

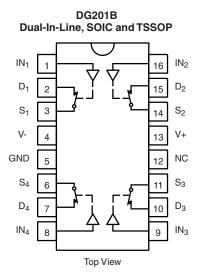
BENEFITS

- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Superior to DG201A, DG202
- Space savings (TSSOP)

APPLICATIONS

- Industrial instrumentation
- Test equipment
- Communications systems
- Disk drives
- Computer peripherals
- Portable instruments
- · Sample-and-hold circuits

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE						
Logic DG201B DG202B						
0	ON	OFF				
1	OFF	ON				

 $\begin{array}{l} \text{Logic "0"} \leq 0.8 \ \text{V} \\ \text{Logic "1"} \geq 2.4 \ \text{V} \end{array}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

Document Number: 70037 S11-0800-Rev. J, 25-Apr-11 This document is subject to change without no



COMPLIANT

This document is subject to change without notice. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Siliconix



ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 55 °C to 125 °C	16 pin CorDIP	DG201BAK				
- 55 °C to 125 °C	16-pin CerDIP	DG202BAK				
	16 pin Plantia DIP	DG201BDJ DG201BDJ-E3				
	16-pin Plastic DIP	DG202BDJ DG202BDJ-E3				
		DG201BDY DG201BDY-E3 DG201BDY-T1 DG201BDY-T1-E3				
- 40 °C to 85 °C	16-pin narrow SOIC	DG202BDY DG202BDY-E3 DG202BDY-T1 DG202BDY-T1-E3				
	16 pin TSSOR	DG201BDQ DG201BDQ-E3 DG201BDQ-T1 DG201BDQ-T1-E3				
	16-pin TSSOP	DG202BDQ DG202BDQ-E3 DG202BDQ-T1 DG202BDQ-T1-E3				

Parameter		Limit	Unit	
Voltages Referenced, V+ to V-		44		
GND		25	v	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	v	
Current (Any terminal)		30	mA	
Peak Current S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	ШA	
Storogo Tomporaturo	(AK, DK suffix)	- 65 to 150	°C	
Storage Temperature	(DJ, DY, DQ suffix)	- 65 to 125		
	16-pin plastic DIP ^c	470		
Power Dissipation (Package) ^b	16-pin narrow SOIC and TSSOP ^d	640	mW	
Power Dissipation (Package)*	16-pin CerDIP ^e	900		
	LCC-20 ^f	750	1	

Notes:

a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 6.5 mW/°C above 75 °C.

d. Derate 7.6 mW/°C above 75 °C.

e. Derate 12 mW/°C above 75 °C.

f. Derate 10 mW/°C above 75 °C.

www.vishay.com 2 Document Number: 70037 S11-0800-Rev. J, 25-Apr-11



Vishay Siliconix

SCHEMATIC DIAGRAM (typical channel)

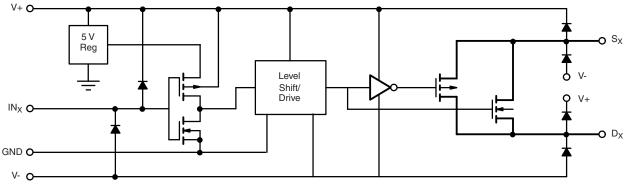


Figure 1.

SPECIFICATIONS	a								
		Test Conditions			A Suffix		D Suffix		
		Unless Specified			- 55 °C to 125 °C		- 40 °C to 85 °C		-
Parameter	Symbol	V+ = 15 V, V- = - 15 V V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Uni
Analog Switch	Cymbol	VIN - 2.4 V, 0.0 V	Temp.	196.	wiiii.	max.		max.	011
Analog Signal Range ^e	V _{ANALOG}		Full	1	- 15	15	- 15	15	V
Drain-Source			Room	45		85		85	
On-Resistance	R _{DS(on)}	$V_{D} = \pm 10 \text{ V}, \text{ I}_{S} = 1 \text{ mA}$	Full			100		100	Ω
R _{DS(on)} Match	$\Delta R_{DS(on)}$	-	Room	2					
Source Off Leakage	I _{S(off)}	$V_{S} = \pm 14 \text{ V}, V_{D} = \pm 14 \text{ V}$	Room	± 0.01	- 0.5	0.5	- 0.5	0.5	
Current	-3(011)		Full	0.04	- 20	20	- 5	5	
Drain Off Leakage Current	I _{D(off)}	$V_{D} = \pm 14 \text{ V}, \text{ V}_{S} = \pm 14 \text{ V}$	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	nA
Drain On Leakage			Room	±0.02	- 0.5	0.5	- 0.5	0.5	
Current	I _{D(on)}	$V_{S} = V_{D} = \pm 14 V$	Full	- 0.01	- 40	40	- 10	10	
Digital Control				1				•	•
Input Voltage High	V _{INH}		Full		2.4		2.4		L V
Input Voltage Low	V _{INL}		Full			0.8		0.8	V
Input Current	I _{INH} or I _{INL}	V _{INH} or V _{INL}	Full		- 1	1	- 1	1	μA
Input Capacitance	C _{IN}		Room	5					pF
Dynamic Characteristics	;			•				•	
Turn-On Time	t _{ON}		Room	120		300		300	
	UN	$V_{\rm S} = 2 V$	Full						ns
Turn-Off Time	t _{OFF}	see switching time test circuit	Room Full	65		200		200	-
		C _L = 1000 pF, V _g = 0 V	Full						
Charge Injection	Q	$R_{g} = 0 \Omega$	Room	1					pC
Source-Off Capacitance	C _{S(off)}	0	Room	5					
Drain-Off Capacitance	C _{D(off)}	$V_{S} = 0 V$, f = 1 MHz	Room	5					рF
Channel On Capacitance	C _{D(on)}	$V_{D} = V_{S} = 0 V$, f = 1 MHz	Room	16					
Off Isolation	OIRR		Room	90					
Channel-to-Channel	V	$C_L = 15 \text{ pF}, R_L = 50 \Omega$ V _S = 1 V _{BMS} , f = 100 kHz	Room	95					dE
Crosstalk	X _{TALK}	•S = • • RMS, • = • • • • • • • •	HUUIII	95					
Power Supply				1		1		1	1
Positive Supply Current	l+		Room Full			50 100		50 100	
		$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room		- 1	100	- 1	100	μA
Negative Supply Current	I-		Full		- 5		- 5		
Power Supply Range for	V.		Full			+ 00		+ 00	v
Continuous Operation	V _{OP}		Fuil		± 4.5	± 22	± 4.5	± 22	V

Document Number: 70037 S11-0800-Rev. J, 25-Apr-11

Vishay Siliconix



SPECIFICATIONS (for Single Supply) ^a										
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C			
Parameter	Symbol	V+ = 12 V, V- = 0 V V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit	
Analog Switch										
Analog Signal Range ^e	V _{ANALOG}		Full		0	12	0	12	V	
Drain-Source On-Resistance	R _{DS(on)}	V _D = 3 V, 8 V, I _S = 1 mA	Room Full	90		160 200		160 200	Ω	
Dynamic Characteristics										
Turn-On Time	t _{ON}	V _S = 8 V	Room	120		300		300		
Turn-Off Time	t _{OFF}	see switching time test circuit	Room	60		200		200	ns	
Charge Injection	Q	$C_L = 1 \text{ nF}, V_{gen} = 6 \text{ V}$ $R_{gen} = 0 \Omega$	Room	4					рС	
Power Supply	Power Supply									
Positive Supply Current	l+	$V_{\rm res} = 0 {\rm or} {\rm F} V_{\rm r}$	Room Full			50 100		50 100		
Negative Supply Current	I-	V _{IN} = 0 or 5 V	Room Full		- 1 - 5		- 1 - 5		μA	
Power Supply Range for Continuous Operation	V _{OP}		Full		+ 4.5	+ 25	+ 4.5	+ 25	V	

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

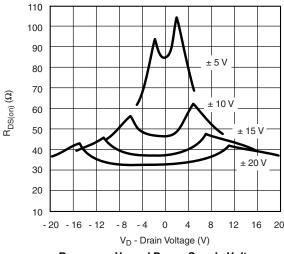
f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

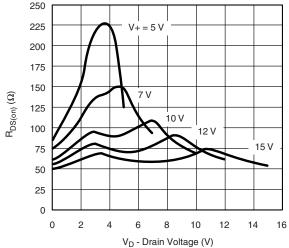


Vishay Siliconix

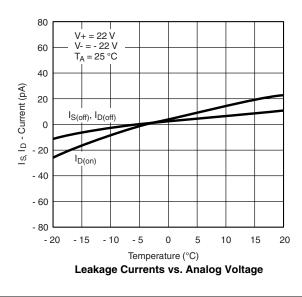
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

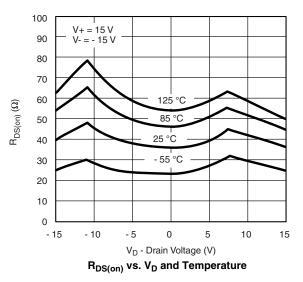


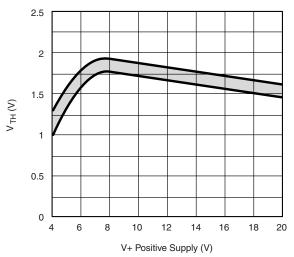
R_{DS(on)} vs. V_D and Power Supply Voltages



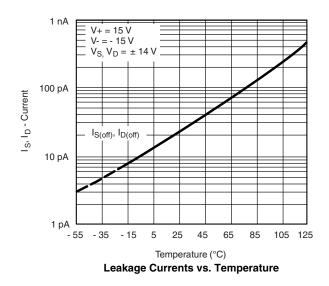
 $R_{DS(on)}$ vs. V_D and Single Power Supply Voltages







Input Switching Threshold vs. Supply Voltage

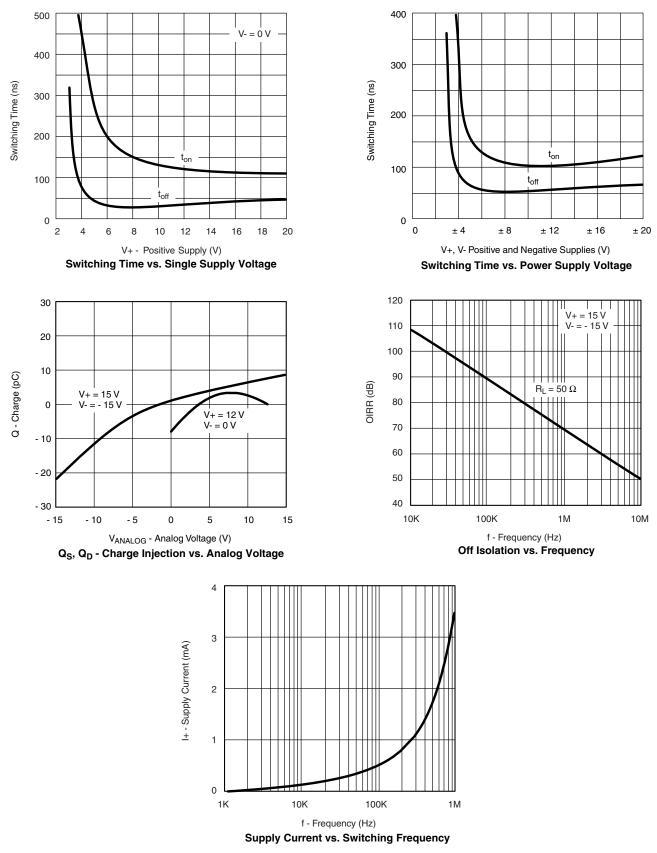


Document Number: 70037 S11-0800-Rev. J, 25-Apr-11 This document is subject to change without notice. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

www.vishay.com

Vishay Siliconix





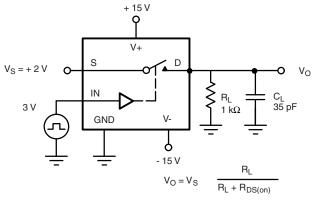
Document Number: 70037 S11-0800-Rev. J, 25-Apr-11

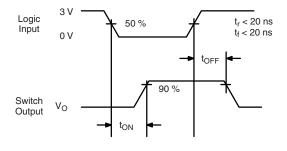
SHA



Vishay Siliconix

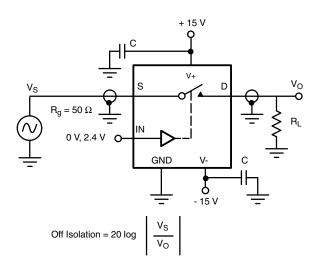
TEST CIRCUITS



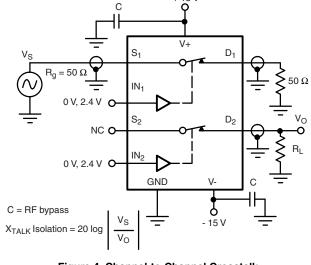


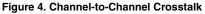
+ 15 V

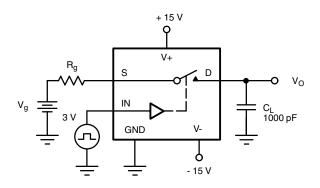
Figure 2. Switching Time

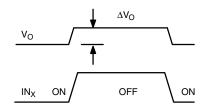












 ΔV_O = measured voltage error due to charge injection The charge injection in coulombs is Q = CL x ΔV_O

Figure 5. Charge Injection

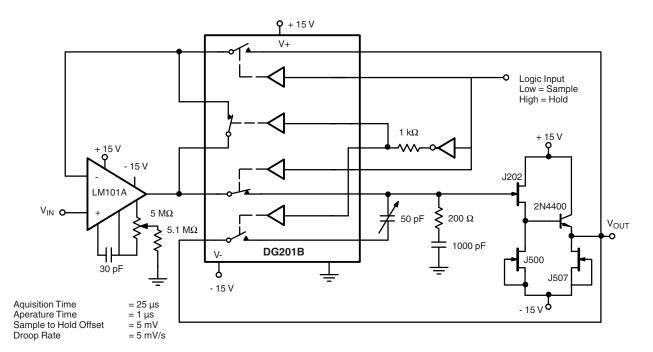
Document Number: 70037 S11-0800-Rev. J, 25-Apr-11

www.vishay.com

Vishay Siliconix



APPLICATIONS





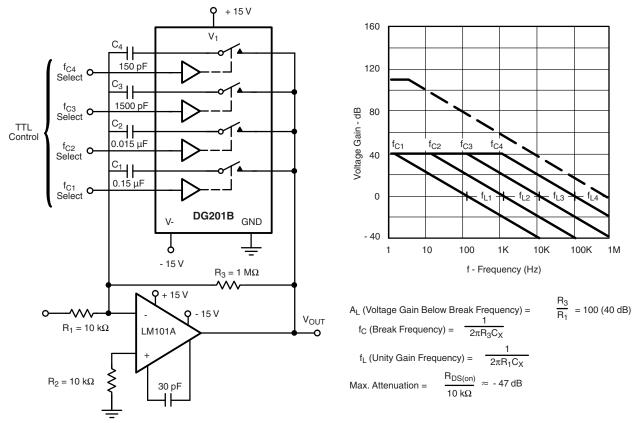


Figure 7. Active Low Pass Filter with Digitally Selected Break Frequency

www.vishay.com 8



DG201B, DG202B Vishay Siliconix

APPLICATIONS

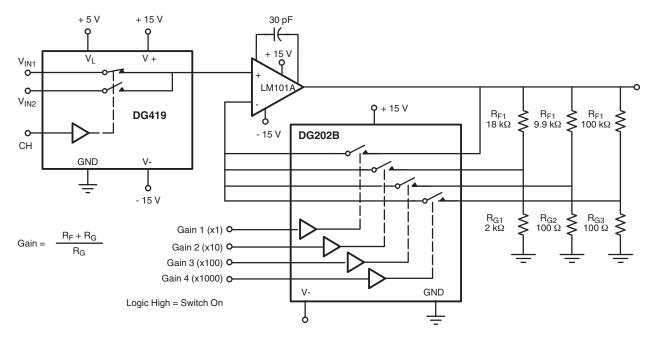


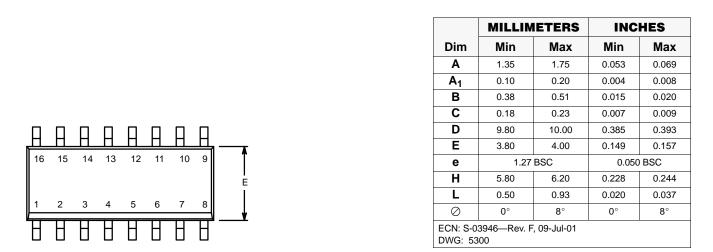
Figure 8. A Precision Amplifier with Digitally Programable Input and Gains

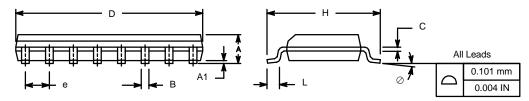
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70037.



SOIC (NARROW): 16-LEAD

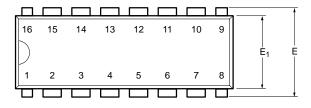
JEDEC Part Number: MS-012

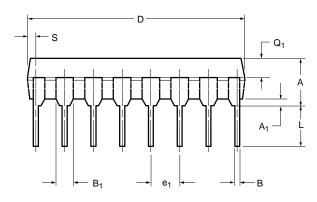


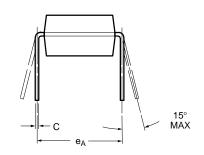




PDIP: 16-LEAD







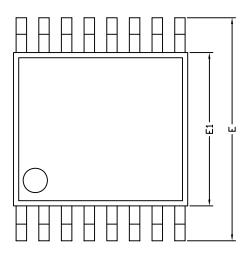
	MILLIN	IETERS	INC	HES		
Dim	Min	Max	Min	Max		
Α	3.81	5.08	0.150	0.200		
A ₁	0.38	1.27	0.015	0.050		
В	0.38	0.51	0.015	0.020		
B ₁	0.89	1.65	0.035	0.065		
С	0.20	0.30	0.008	0.012		
D	18.93	21.33	0.745	0.840		
E	7.62	8.26	0.300	0.325		
E ₁	5.59	7.11	0.220	0.280		
e ₁	2.29	2.79	0.090	0.110		
e _A	7.37	7.87	0.290	0.310		
L	2.79	3.81	0.110	0.150		
Q ₁	1.27	2.03	0.050	0.080		
S	0.38	1.52	.015	0.060		
	ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

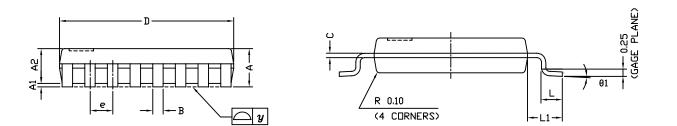


Package Information

Vishay Siliconix

TSSOP: 16-LEAD





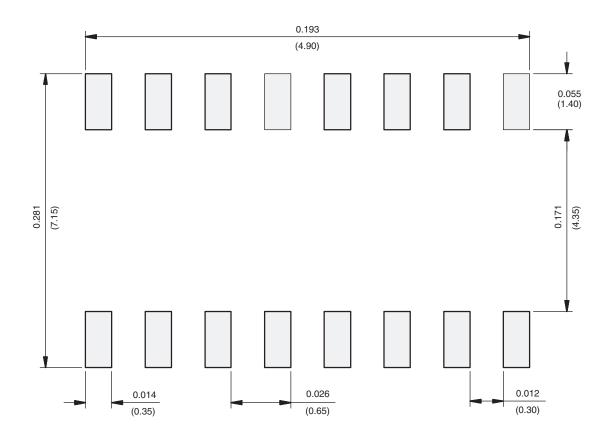
	C	DIMENSIONS IN MILLIMETERS				
Symbols	Min	Nom	Мах			
A	-	1.10	1.20			
A1	0.05	0.10	0.15			
A2	-	1.00	1.05			
В	0.22	0.28	0.38			
С	-	0.127	-			
D	4.90	5.00	5.10			
E	6.10	6.40	6.70			
E1	4.30	4.40	4.50			
е	-	0.65	-			
L	0.50	0.60	0.70			
L1	0.90	1.00	1.10			
у	-	-	0.10			
θ1	0°	3°	6°			
ECN: S-61920-Rev. D, 23 DWG: 5624	-Oct-06					



PAD Pattern

Vishay Siliconix

RECOMMENDED MINIMUM PAD FOR TSSOP-16



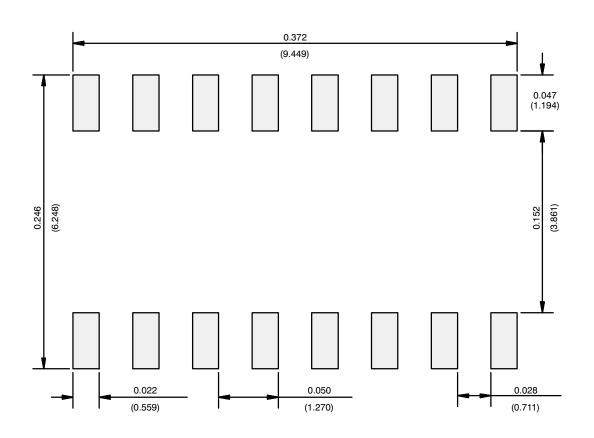
Recommended Minimum Pads Dimensions in inches (mm)

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2024